

## Photo DMOS-FET Relay

### Description

The **LU710** is a 2-Form B solid state relay in a 8 pin SMD package that employs optically coupled MOSFET technology to provide 3750V/5000V of input to output isolation. The optically coupled input is controlled by a highly efficient GaAlAs infrared LED and MOS FETs on the output side.

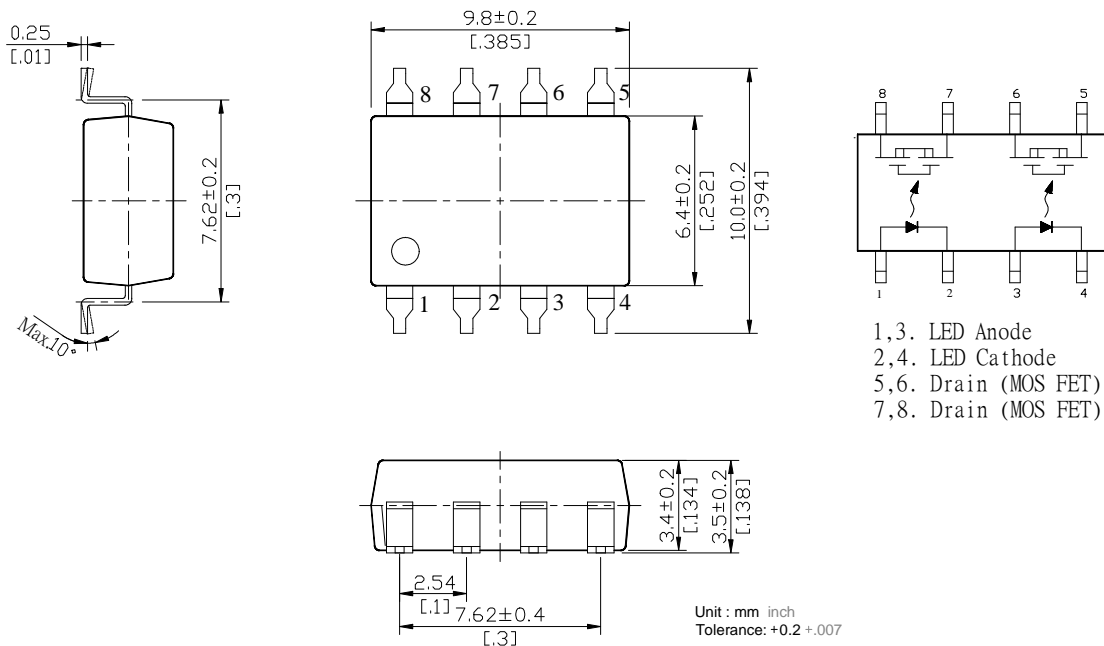
### Features

- Low driver power requirements (TTL/CMOS Compatible)
- Contact form: Normally-On (2b)
- Load voltage: 400V max.
- On-Resistance: 50Ω max.
- 3750 / 5000Vrms Input/Output isolation
- Tape & Reel version available

### Applications

- Telecommunications (PC, Electronic notepad)
- Measuring and Testing equipment
- Industrial control
- Security equipments
- High speed inspection machine

### Outline Dimensions



## Photo DMOS-FET Relay Specifications

### Part Name: LU710

(Load voltage: 400V / Load current: 120mA)

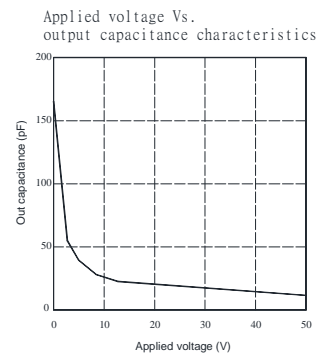
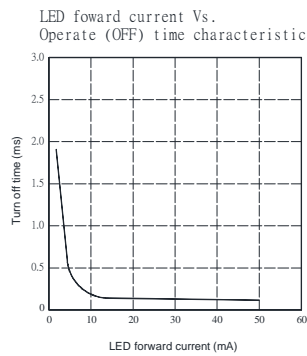
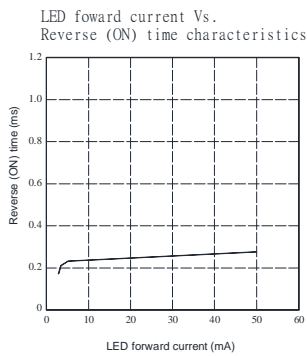
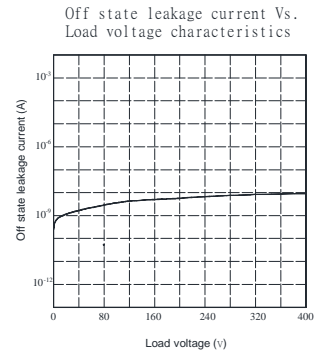
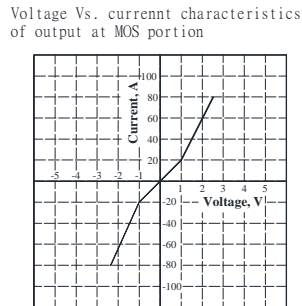
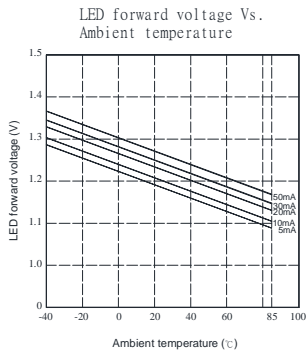
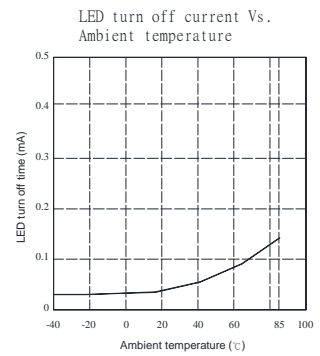
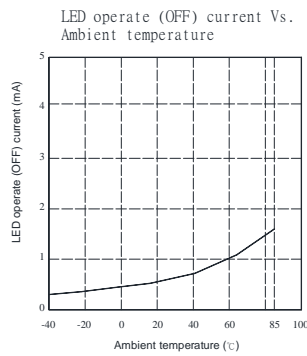
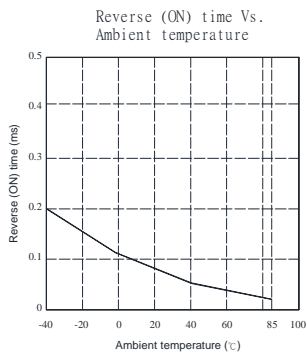
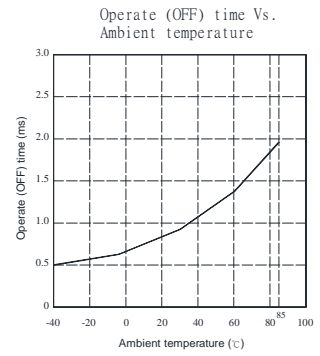
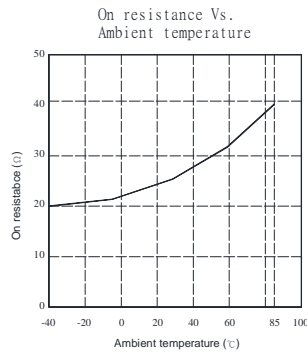
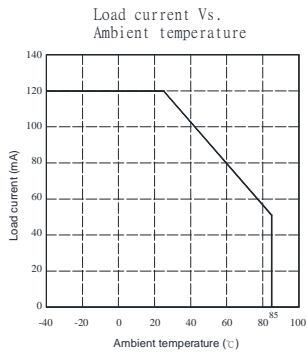
#### Absolute Maximum Ratings (Ambient Temperature: 25°C)

Item		Symbol	Value	Units	Note
Input	Continuous LED Current	IF	50	mA	
	Peak LED Current	IFP	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	PIn	75	mW	
Output	Load Voltage	VL	400	V(AC peak or DC)	
	Load Current	IL	120	mA	
	Peak Load Current	IPeak	0.3	A	1ms(1 pulse)
	Output Power Dissipation	Pout	500	mW	
Total Power Dissipation		PT	550	mW	
I/O Breakdown Voltage		VI/O	3750	Vrms	RH=60%, 1min
I/O Breakdown Voltage(Suffix-V)		VI/O	5000	Vrms	RH=60%, 1min
Operating Temperature		Topr	-40 to +85	°C	
Storage Temperature		Tstg	-40 to +100	°C	
Pin Soldering Temperature		Tsol	260	°C	10 sec max.

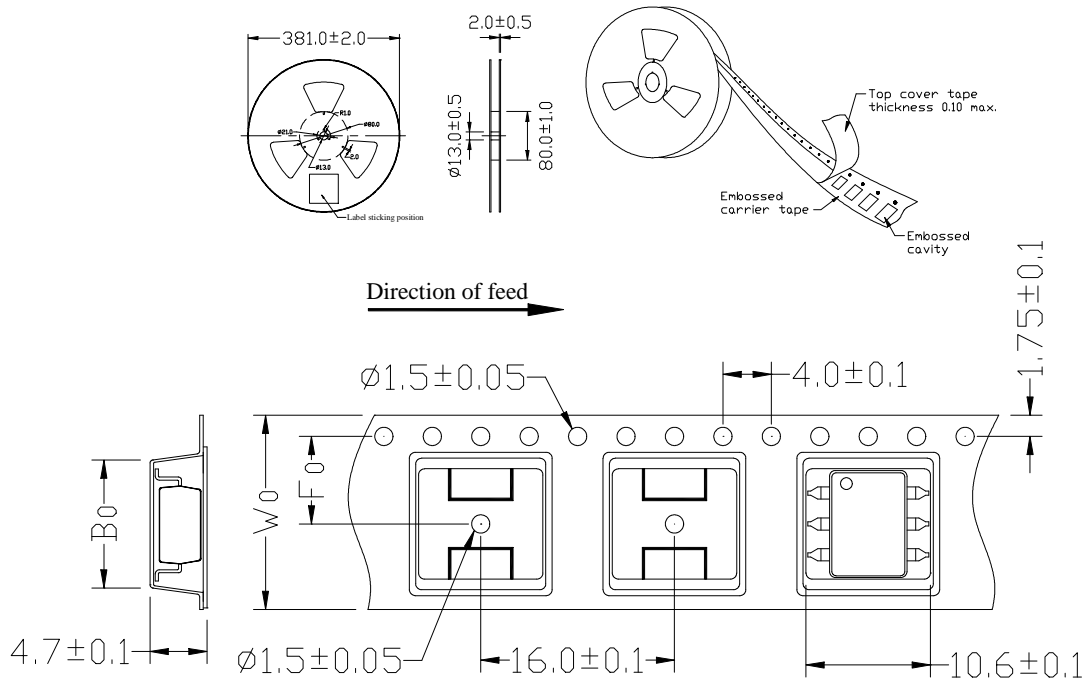
#### Electrical Specifications (Ambient Temperature: 25°C)

Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	VF		1.2	1.5	V	IF=10mA
	Operation LED Current	IFon		0.5	5.0	mA	
	Recovery LED Current	IFoff		0.35	0.5	mA	
	Recovery LED Voltage	VFoff	0.5			V	
Output	On-Resistance	Ron		20	50	Ω	IF=0mA,IL=100mA, Time to flow is within 1 sec.
	Off-State Leakage Current	ILeak			10	uA	IF=5mA,VL=400V
	Output Capacitance	Cout		165		pF	IF=5mA,VL=0, f=1MHz
Transmission	Turn-On Time	Ton		0.02	1.0	ms	IF=10mA, IL=100mA
	Turn-Off Time	Toff		0.5	3.0	ms	
Coupled	I/O Isolation Resistance	R/I/O	10 <sup>10</sup>			Ω	DC500V
	I/O Capacitance	C/I/O		0.8		pF	f=1MHz

## Reference Data



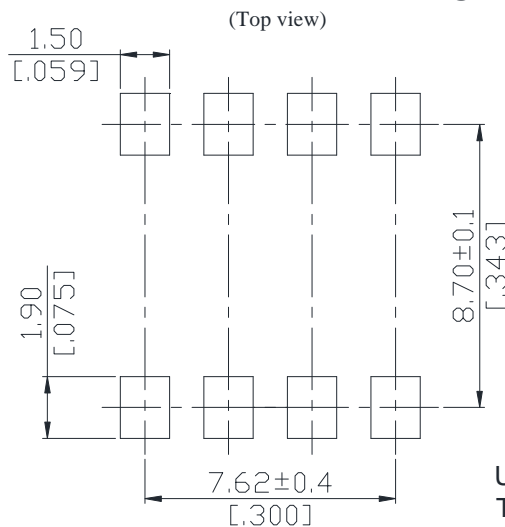
## Taping Specifications for Surface Mount Devices



Unit: mm

TYPE	B0±0.1	F0±0.1	W0±0.1	15"REEL/PCS
8P	10.3	11.5	24	1000

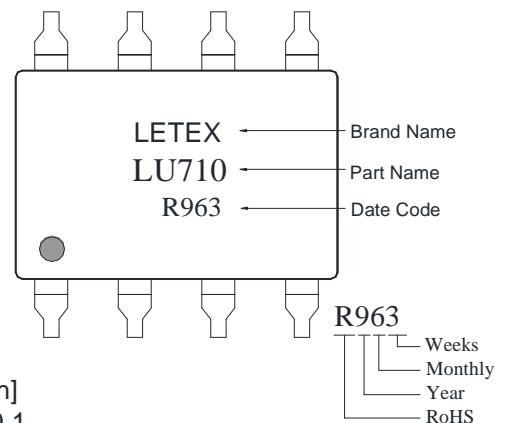
### Recommended Mounting Pad



Unit : mm [inch]  
Tolerance : ±0.1

### Marking

(Each photo MOS Relay shall be marked with the following information)



- Note: 1. There shall be leader of 230 mm minimum which may consist of carrier and or cover tape follower by a minimum of 160 mm of carrier tape sealed with cover tape.
2. There shall be a minimum of 160 mm of empty component pockets sealed with cover tape.
3. Devices are pockets in accordance with EIA standard EIA-481-A and specifications given above.